NSN 5961-00-159-7246

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-159-7246 **Inclosure Material:** Metal **Overall Length:** 1.639 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: T0-118 **Electrode Internally-electrically Connected To Case:** Gate **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 1.690 inches **Thread Size:** 0.175 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 500.0 off-state voltage, rms total **Current Rating Per Characteristic:** 400.00 amperes forward current, total rms horsepower metric **Maximum Operating Tempurature Per Measurement Point:** 125.00 degrees celsius junction **Special Features:** Junction pattern arrangement: pnpn **Thread Series Designator: Terminal Type And Quantity:** 1 insulated wire lead w/terminal lug and 2 uninsulated wire lead w/terminal lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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